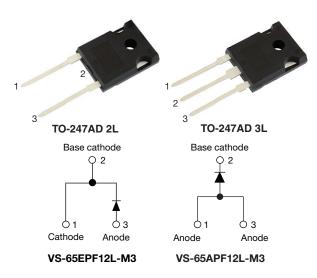
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VS-65EPF12L-M3, VS-65APF12L-M3

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Fast Soft Recovery Rectifier Diode, 65 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	65 A						
V _R	1200 V						
V _F at I _F	1.42 V						
I _{FSM}	830 A						
t _{rr}	95 ns						
T _J max.	150 °C						
Package	TO-247AD 2L, TO-247AD 3L						
Circuit configuration	Single						
Snap factor	0.6						

FEATURES

• Very low forward voltage drop and short reverse recovery time



Glass passivated pellet chip junction

COMPLIANT HALOGEN

- Designed and qualified according to JEDEC®-JESD 47
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- AEC-Q101 qualified P/N available (VS-65EPF12LHM3, VS-65APF12LHM3)
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-65EPF12L-M3, VS-65APF12L-M3 soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Sinusoidal waveform	65	A					
V _{RRM}		1200	V					
I _{FSM}		830	A					
t _{rr}	1 A, 100 A/µs	95	ns					
V _F	30 A, T _J = 25 °C	1.20	V					
TJ		-40 to +150	°C					

VOLTAGE RATINGS			
PART NUMBER V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RBM} AT 150 ℃ mA
VS-65EPF12L-M3	1200	1300	16
VS-65APF12L-M3	1200	1300	10

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ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	$T_C = 113 \text{ °C}$, 180° conduction half sine wave	65						
Maximum peak one cycle	less.	10 ms sine pulse, rated V_{RRM} applied	700	А					
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	830						
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	2450	A ² s					
Waximum r-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	3460	A-S					
Maximum I²√t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	34 600	A²√s					

ELECTRICAL SPECIFICATIONS								
PARAMETER	VALUES	UNITS						
Maximum forward voltage drop	V _{FM}	65 A, T _J = 25 °C		1.42	V			
Forward slope resistance	r _t	T.I = 150 °C		4.6	mΩ			
Threshold voltage	V _{F(TO)}	1J = 150 C		0.9	V			
Maximum reverse leakage current		$T_J = 25 \text{ °C}$		0.1	mA			
Maximum reverse leakage current	IRM	T _J = 150 °C	V_R = rated V_{RRM}	16	ШA			

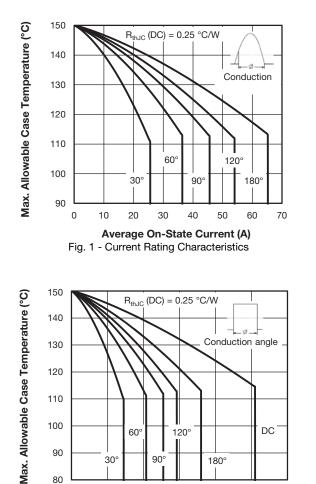
RECOVERY CHARACTERISTICS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	t ↑			
Reverse recovery time	t _{rr}	I _F at 60 A _{pk}	480	ns	I _{FM} t			
Reverse recovery current	I _{rr}	25 A/µs	8	А				
Reverse recovery charge	Q _{rr}	25 °C	2.7	μC	dir/ dt/Q,,			
Snap factor	S	Typical	0.6		I V I _{RM(REC)}			

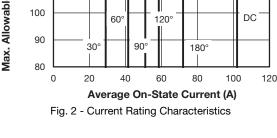
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storage temperature range		TJ, T _{Stg}		-40 to +150	°C			
Maximum thermal resistance, unction to case		R _{thJC}	DC operation	0.25				
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.25				
Approvimente weight				6	g			
Approximate weight				0.21	oz.			
Mounting torque	minimum			6 (5)	kgf⋅cm			
Mounting torque	maximum			12 (10)	(lbf ⋅ in)			
		Case style T		65EPF12L				
Marking device			Case style TO-247AD 3L	65APF12L				

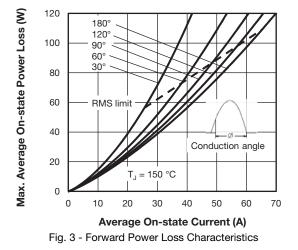


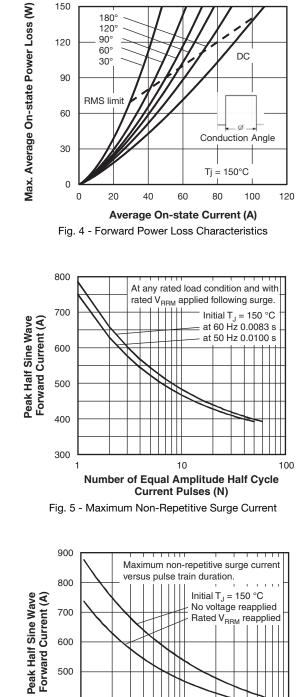
VS-65EPF12L-M3, VS-65APF12L-M3

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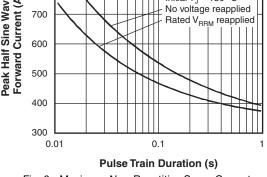


Fig. 6 - Maximum Non-Repetitive Surge Current

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3

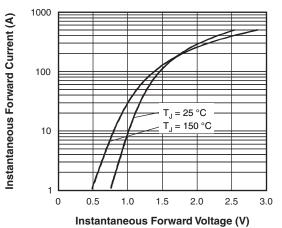
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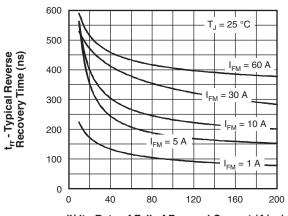


VS-65EPF12L-M3, VS-65APF12L-M3

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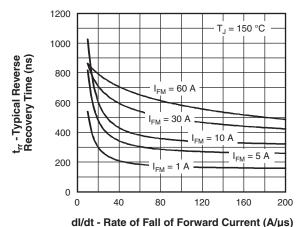
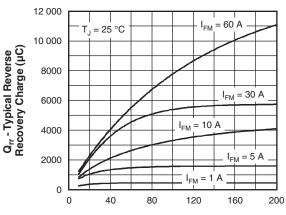
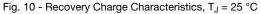
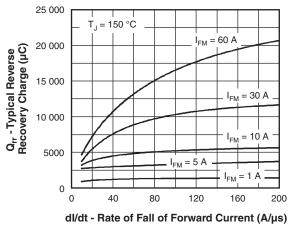


Fig. 9 - Recovery Time Characteristics, T_J = 150 °C



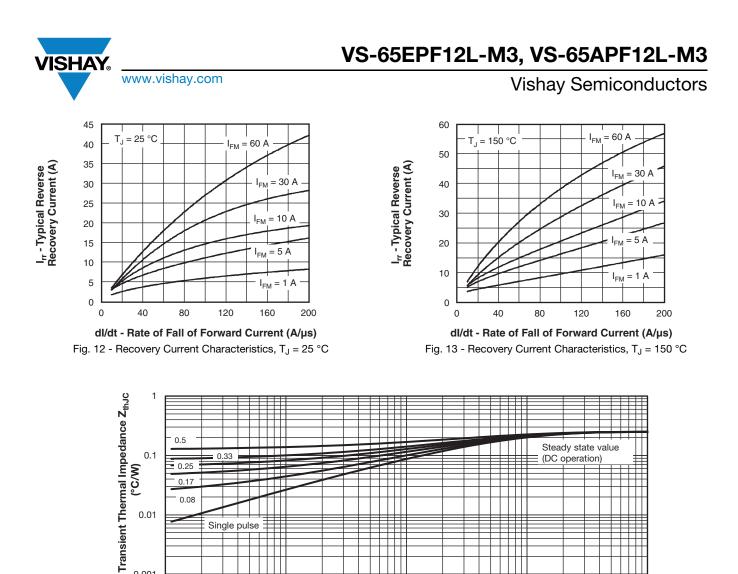
dl/dt - Rate of Fall of Forward Current (A/µs)







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0.01

Square Wave Pulse Duration (s)

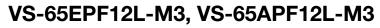
Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

0.1

1

0.001

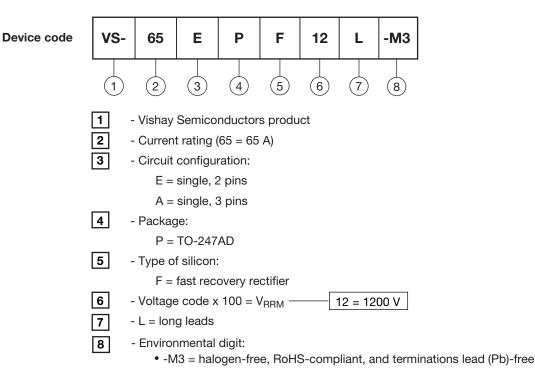
0.001



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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)								
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTIO								
VS-65EPF12L-M3	25	500	Antistatic plastic tubes					
VS-65APF12L-M3	25	500	Antistatic plastic tubes					

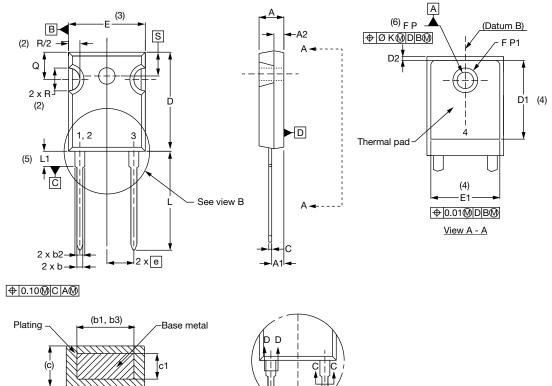
LINKS TO RELATED DOCUMENTS						
Dimensions	TO-247AD 2L	www.vishay.com/doc?95536				
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626				
Part marking information	TO-247AD 2L	www.vishay.com/doc?95648				
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007				



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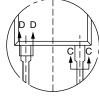
TO-247AD 2L

DIMENSIONS in millimeters and inches



	(4)
Section C -	- C, D - D

(b, b2)



View	В
------	---

SYMBOL	MILLIM	IETERS	INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	23	STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			E	15.29	15.87	0.602	0.625	3
A1	2.21	2.59	0.087	0.102			E1	13.46	-	0.53	-	
A2	1.50	2.49	0.059	0.098			е	5.46	BSC	0.215	5 BSC	
b	0.99	1.40	0.039	0.055			ØK	0.2	254	0.0	010	
b1	0.99	1.35	0.039	0.053			L	19.81	20.32	0.780	0.800	
b2	1.65	2.39	0.065	0.094			L1	3.71	4.29	0.146	0.169	
b3	1.65	2.34	0.065	0.092			ØР	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035			Ø P1	-	6.98	-	0.275	
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4		S	5.51	BSC	0.217	' BSC	
D2	0.51	1.35	0.020	0.053								

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1

(5) Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

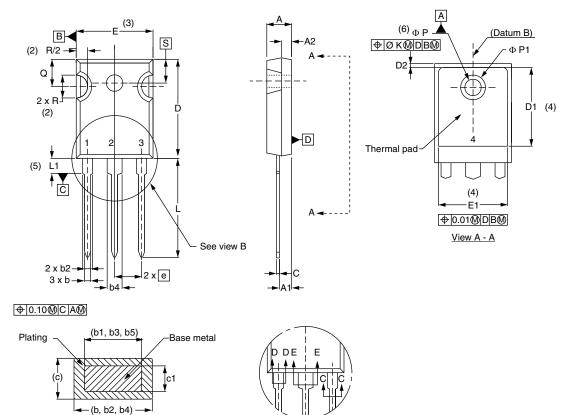
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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(4) <u>Section C - C, D - D, E - E</u>

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NUTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215 BSC		
ØК	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

Notes

- ⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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 1
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